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(54) Electron-emitting device.

(57) An electron-emitting device is provided which comprises a laminate comprising an insulating layer (5) held between a pair of electrodes (1,2) opposing each other, wherein an electron-emitting region (3) insulated from said electrodes is formed at a side end surface of the insulating layer (5) formed at the part at which the electrodes oppose each other, and electrons are emitted from said electron-emitting region (3) by applying a voltage between said elec-

trodes. A method for preparing the electron-emitting device is also provided.

FIG.1

